

Mechanical dimensions of Module:



L206HL top view and side view (mm)

ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

The following table shows the absolute maximum state in abnormal situation, more than the limit value will likely result in permanent damage to the module.

Parameter	Min	Тур.	Max	Unit
VBAT	3.3	3.8	4.4	V
Peak current	-0.3	-	3	А
Digital signal input voltage	-0.3	-	3.1	V
Analog input voltage	-0.3	-	3.1	V
Working temperature	-40	25	+85	°C
Storage temperature	-45	25	+90	°C

Absolute Maximum Ratings

Digital Interface Characteristics

Digital Interface Characteristics



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Parameter	Description	Min	Тур.	Max	Unit
VIH	Input high level	2.1	-	3.1	V
VIL	Input high level	0	-	0.7	V
VOH	Input high level	2.5	-	3.1	V
VOL	Input high level	0	-	0.3	V
VIH	Input high level	2.1	-	3.1	V

* Apply to the GPIO, I2C, UART, PCM digital interface, etc.

VSIM Characteristics

SIM card interface characteristics

Parameter	Description	Min	Тур.	Max	Unit
VO	Output voltage	1.65	1.8	1.95	V
vo	Output voltage	2.8	3.0	3.2	V
IO	Output current	-	-	60	mA

Current Consumption

Current consumption

Parameter	Conditions	Min	Тур.	Max	Unit
Bottom current	Shutdown mode		0.16		mA
	Sleep mode		1		mA
	Standby mode		10.6		mA
Working current	Voice (maximum power)		280		mA
	Data transfer modeGPRS(1Rx,4Tx)		493		mA
	Data transfer modeGPRS(3Rx,2Tx)		386		mA
Peak current	Maximum power burst current			2.0	А
	Data transfer modeGPRS(3Rx,2Tx)		413		mA



ESD

In the use of the module, due to the human body static electricity, electric charge and friction between the two kinds of static electricity generated by various means of discharge to the module, may cause some damage, so ESD protection must pay attention, whether in the development, production assembly, testing process, especially in product design, should be taken to prevent ESD protection measures. Such as circuit design in the interface or vulnerable to the ESD point to increase the ESD protection, the production of anti-static gloves, etc.. Because the module is not specifically designed for electrostatic discharge protection, so in the production, assembly and operation module must pay attention to the electrostatic protection. The performance of the module test parameters in the following table:

ESD performance parameters (temperature: 25, humidity: 45%)

PIN	Contact discharge	Air discharge
VBAT	$\pm 5 \text{KV}$	$\pm 10 \text{KV}$
GND	$\pm 5 \text{KV}$	$\pm 10 \text{KV}$
RXD,TXD	$\pm 1 \text{KV}$	$\pm 6 \mathrm{KV}$
RF_ANT	$\pm 5 \text{KV}$	$\pm 10 \text{KV}$
MIC_P/N		$\pm \epsilon V M$
RCV_P/N	$\pm 2\mathbf{K}\mathbf{v}$	⊥ 0K V
PWRKEY	$\pm 2KM$	$\pm \epsilon V M$
RESET_N	<u>+</u> 3K V	<u> </u>

ESD performance parameters

RF performance

• RF output power

Following table lists the conducted output power of modules, compliant with 3GPP TS 05.05 SPEC.

EGSM900 and GSM850 conducted output power

PCL	Output power(dBm)	Tolerance (dB) for conditions	
	Nominal	Normal	Extreme
5	32.5	± 0.4	± 2
6	30.8	±1	± 2
7	29	±1	± 2
8	27	±1	± 2
9	25	±1	± 2
10	23	±1	±2
11	21	<u>±1</u>	<u>±2</u>



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12	19	±1	± 2
13	17	±1	± 2
14	15	± 1	± 2
15	13	±1.5	± 2
16	11	±1.5	± 2
17	9	±1.5	± 2
18	7	\pm 1.5	± 5

PCL	Output power(dBm)	Tolerance (dB) for conditions	
	Nominal	Normal	Extreme
0	29.5	± 0.4	±2
1	27.5	±1	± 2
2	26	±1	± 2
3	24	±1	± 2
4	22	± 1	± 2
5	20	±1	± 2
6	18	±1	± 2
7	16	±1	± 2
8	14	± 1	± 2
9	12	±1.5	± 2
10	10	± 1.5	± 2
11	8	±1.5	± 2
12	6	±1.5	± 2
13	4	±1.5	±2
14	2	± 1.5	± 5
15	0	± 2	±5

DCS1800 and PCS1900 conducted output power

• Module conduction receiver sensitivity

The followingtable lists the module's conduction reception sensitivity and is tested under static conditions.

Conduction sensitivity

Band	Receiving sensitivity (Typ.)
GSM850	≦-108dBm
EGSM900	≦-108dBm
DCS1800	≦-108dBm

PCS1900

• Module frequency band

The followingtable lists the module's working frequency bands, compliant with the TS 3GPP 5.05 specification.

Module frequency band

Band	Receiving sensitivity (Typ)	Receiving sensitivity (Max))
GSM850	869 ~ 894MHz	824 ~ 849MHz
EGSM900	925 ~ 960MHz	880 ~ 915MHz
DCS1800	1805 ~ 1880MHz	1710 ~ 1785MHz
PCS1800	1930 ~ 1990MHz	1850 ~ 1910MHz



MANUFACTURING

L206HL top and bottom view



L206HL top and bottom view



Soldering

Recommend reflow temperature profile

The Moisture Sensitivity Level (MSL)

L206HL module complies with the humidity level 3. At a temperature of <30 degrees and relative humidity of <60% of the environmental conditions, dry pack to perform J-STD-020C specification according to IPC / JEDEC standard. At a temperature of <40 degrees and a relative humidity of <90% of the environmental conditions, in the case of unopened shelf life of at least six months. After unpacking, Table29 shows the module shelf life at different times corresponding to the level of humidity.

TheMoistureSensitivityLevel (MSL)	Floor Life(out of bag) at factory ambient≦+30 /60%RH
1 RH ℃ condition	Unlimited at $\leq +30/85\%$
2	1 Year
2a	4 weeks
3	168 hours
4	72 hours
5	48 hours
5a	24 hours
6	Mandatory bake before use. After bake, it must be reflowed
	within the time limit specified on the label.

Moisture sensitivity level and floor life

After unpacking,<30 degrees in temperature and relative humidity <60% environmental conditions, 168 hours in the SMT patch. If not meet the above conditions need to be baked.

NOTES: For product handling, storage, processing, IPC / JEDEC J-STD-020C must be followed

Baking Requirements

Due to the humidity sensitive characteristics of the L206HL module, the L206HL is a vacuum packaging, which can be stored for 6 months without damage to the package, and the ambient temperature is less than 40 C and the relative humidity is less than 90%. To meet one of



the following conditions, the process of reflow soldering should be performed before the full bake,

or the module may cause permanent damage to the process.

- 1. Vacuum packing damage or leakage
- 2. The module is exposed in the air for 168 hours or more
- 3. The module is exposed in air for 168 hours, not meet the temperature <30 degrees and

relative humidity of the environment conditions <60%

Baking requirements

Baking temperature	Humidity	Baking time
$40^{\circ} \text{ C}\pm5^{\circ} \text{ C}$	<5%	192 Hours
$120^{\circ} \text{ C}\pm5^{\circ} \text{ C}$	<5%	4 Hours

RELATED DOCUMENTS

Related documents

NO.	Documents	Note
[1]	AT_DOCUMENT_R1.04	
[2]	ITU-T Draft new recommendation V.25ter:	Serial asynchronous automatic dialing and control
[3]	GSM 07.07:	Digital cellular telecommunications (Phase 2+); AT command set for GSM Mobile Equipment (ME)
[4]	GSM 07.10:	Support GSM 07.10 multiplexing protocol
[5]	GSM 07.05:	Digital cellular telecommunications (Phase 2+); Use of Data Terminal Equipment – Data Circuit terminating Equipment (DTE – DCE) interface for Short Message Service (SMS) and Cell Broadcast Service (CBS)
[6]	GSM 11.14:	Digital cellular telecommunications system (Phase 2+); Specification of the SIM Application Toolkit for the Subscriber Identity Module – Mobile Equipment (SIM – ME) interface
[7]	GSM 11.11:	Digital cellular telecommunications system (Phase 2+); Specification of the Subscriber Identity Module – Mobile Equipment (SIM – ME) interface